Exact Exchange in Density Functional Theory

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Many-body theory involves solving for functions in 3N coordinates: $\Psi(\mathbf{r}_1,\mathbf{r}_2,\ldots,\mathbf{r}_N)$

Density functional theory (DFT) requires solving for functions in 3 coordinates: $n(\mathbf{r})$

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Hohenberg-Kohn Theorems (1964)

- **1** External potential $v(\mathbf{r})$ is uniquely determined by $n(\mathbf{r})$
- 2 The variational principle holds

$$E_0 = E_{v_0}[n_0] < E_{v_0}[n]$$

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DFT is an exact theory for interacting systems in the ground state

Find set of auxilliary single particle orbitals such that

$$\left[-\frac{1}{2}\nabla^2 + v_{\mathsf{s}}(\mathbf{r})\right]\phi_i(\mathbf{r}) = \epsilon_i\phi_i(\mathbf{r})$$

and

$$n(\mathbf{r}) = \sum_{i}^{\text{occ}} |\phi_i(\mathbf{r})|^2.$$

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$$F[n] = T_{\mathsf{s}}[n] + \frac{1}{2} \int d\mathbf{r} \ d\mathbf{r}' \frac{n(\mathbf{r})n(\mathbf{r}')}{|r - r'|} + E_{\mathsf{xc}}[n]$$

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Then

$$v_{\mathsf{s}}[n](\mathbf{r}) = v(\mathbf{r}) + \int d\mathbf{r}' \frac{n(\mathbf{r}')}{|\mathbf{r} - \mathbf{r}'|} + v_{\mathsf{xc}}[n](\mathbf{r})$$

where

$$v_{\mathsf{xc}}[n](\mathbf{r}) = \frac{\delta E_{\mathsf{xc}}[n]}{\delta n(\mathbf{r})}.$$

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First generation: Local density approximation (LDA)

$$E_{\mathsf{xc}}^{\mathsf{LDA}}[n] = \int d\mathbf{r} \ n(\mathbf{r}) e_{\mathsf{xc}}^{\mathsf{unif}}(n(\mathbf{r}))$$

Second generation: Generalised gradient approximations

$$E_{\mathsf{xc}}^{\mathsf{GGA}}[n] = \int d\mathbf{r} \ f(n(\mathbf{r}), \nabla n(\mathbf{r}))$$

$$E_{\text{xc}}^{\text{Meta-GGA}}[n] = \int d\mathbf{r} \ g(n(\mathbf{r}), \nabla n(\mathbf{r}), \tau(\mathbf{r}))$$

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Density functional theory Kohn-Sham equations Exchange-correlation functionals Practicalities

Exchange-correlation functionals

Development of new functionals leads not only to improved accuracy but also correct qualitative features



Third generation: Exact exchange (EXX)

Neglect correlation and use the Hartree-Fock exchange energy

$$E_{\mathsf{x}}[n] = -\frac{1}{2} \sum_{i,j}^{\mathsf{occ}} \int d\mathbf{r} \ d\mathbf{r}' \frac{\phi_i^*(\mathbf{r}) \phi_j^*(\mathbf{r}') \phi_j(\mathbf{r}) \phi_i(\mathbf{r}')}{|\mathbf{r} - \mathbf{r}'|}$$

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Using the functional derivative chain rule:

$$v_{\mathbf{x}}[n](\mathbf{r}) = \sum_{i}^{\mathsf{occ}} \int d\mathbf{r} \ d\mathbf{r}'' \left[\frac{\delta E_{\mathbf{x}}}{\delta \phi_{i}(\mathbf{r}'')} \frac{\delta \phi_{i}(\mathbf{r}'')}{\delta v_{\mathbf{s}}(\mathbf{r}')} + \frac{\delta E_{\mathbf{x}}}{\delta \phi_{i}^{*}(\mathbf{r}'')} \frac{\delta \phi_{i}^{*}(\mathbf{r}'')}{\delta v_{\mathbf{s}}(\mathbf{r}')} \right] \frac{\delta v_{\mathbf{s}}(\mathbf{r}')}{\delta n(\mathbf{r})}$$

$$= \int d\mathbf{r}' \left[\sum_{i}^{\mathsf{occ}} \sum_{j}^{\mathsf{unocc}} \langle \phi_{i} | \hat{v}_{\mathbf{x}}^{\mathsf{NL}} | \phi_{j} \rangle \frac{\phi_{j}^{*}(\mathbf{r}') \phi_{i}(\mathbf{r}')}{\epsilon_{i} - \epsilon_{j}} + \mathsf{c.c.} \right] \frac{\delta v_{\mathbf{s}}(\mathbf{r}')}{\delta n(\mathbf{r})},$$

where

$$\langle \phi_{i\mathbf{k}} | \hat{v}_{\mathbf{x}}^{\mathsf{NL}} | \phi_{j\mathbf{k}} \rangle = \sum_{l\mathbf{k}'}^{\mathsf{occ}} w_{\mathbf{k}'} \int d\mathbf{r} \ d\mathbf{r}' \frac{\phi_{i\mathbf{k}}^*(\mathbf{r}) \phi_{l\mathbf{k}'}(\mathbf{r}) \phi_{l\mathbf{k}'}^*(\mathbf{r}') \phi_{j\mathbf{k}}(\mathbf{r}')}{|\mathbf{r} - \mathbf{r}'|}.$$





Using the linear-response operator

$$\chi(\mathbf{r}, \mathbf{r}') \equiv \frac{\delta n(\mathbf{r})}{\delta v_{s}(\mathbf{r}')}$$

$$= \sum_{i}^{\text{occ}} \sum_{j}^{\text{unocc}} \frac{\phi_{i}^{*}(\mathbf{r})\phi_{j}(\mathbf{r})\phi_{j}^{*}(\mathbf{r}')\phi_{i}(\mathbf{r}')}{\epsilon_{i} - \epsilon_{j}} + \text{c.c.}$$

we have

$$\frac{\delta v_{\mathsf{s}}(\mathbf{r}')}{\delta n(\mathbf{r})} = \tilde{\chi}^{-1}(\mathbf{r}, \mathbf{r}').$$

basis



- Hartree-Fock
- a mean-field theory
- an attempt to solve the quasi-particle equation
- a parameterised correction to LDA
- easy to implement

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Pseudopotentials (PP)

- atomic core is frozen and represented by a non-local potential
- does not react properly to the solid state environment: no relaxation of core states
- planewaves are used as the basis

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Atomic sphere approximation (ASA)

- includes core orbitals
- potential is spherically symmetric
- muffin-tins are space-filling

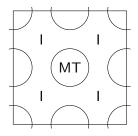
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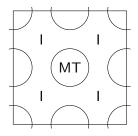
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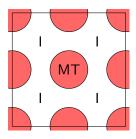
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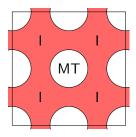


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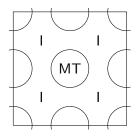


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Basis set

An efficient basis set is required so that the response

$$\chi(\mathbf{r}, \mathbf{r}') \equiv \frac{\delta n(\mathbf{r})}{\delta v_{\mathsf{s}}(\mathbf{r}')}$$

can be inverted

Basis set should not contain constant functions

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Choose the overlap densities

$$\rho_{\alpha}(\mathbf{r}) \equiv \phi_{i\mathbf{k}}^{*}(\mathbf{r})\phi_{j\mathbf{k}}(\mathbf{r}),$$

and complex conjugates, where $\alpha \equiv (i\mathbf{k}, j\mathbf{k})$.

Diagonalise

$$O_{\alpha\beta} \equiv \int d\mathbf{r} \; \rho_{\alpha}^*(\mathbf{r}) \rho_{\beta}(\mathbf{r}),$$

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$$O_{lphaeta} \equiv \int d{f r} \;
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and eliminate eigenvectors with small eigenvalues.

Find transformation matrix C such that if

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ho}_{lpha}(\mathbf{r}) = \sum_{eta} C^{lpha}_{eta} \sum_{\gamma} v^{eta}_{\gamma}
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then

$$\int d\mathbf{r} \; \tilde{\rho}_{\alpha}^*(\mathbf{r}) \tilde{\rho}_{\beta}(\mathbf{r}) = \delta_{\alpha\beta}.$$

The matrix equation

$$CC^{\dagger} = \left(v^{\dagger}Ov\right)^{-1}$$

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By construction $\int d{\bf r} \ \tilde{\rho}_{\alpha}({\bf r}) = 0$, so $\{\tilde{\rho}_{\alpha}\}$ form an ideal basis for inversion of χ

NL Lastly, given $\mathbf{q} \equiv \mathbf{k} - \mathbf{k}'$, the long range coulomb term of the NL matrix elements

$$\langle \phi_{i\mathbf{k}} | \hat{v}_{\mathbf{x}}^{\mathsf{NL}} | \phi_{j\mathbf{k}} \rangle_{\mathsf{LR}} = \sum_{l\mathbf{q}}^{\mathsf{occ}} w_{\mathbf{q}} \frac{4\pi\Omega}{q^2} \rho_{il}^*(\mathbf{q}) \rho_{lj}(\mathbf{q}),$$

where $\rho_{il}(\mathbf{q})$ and $\rho_{lj}(\mathbf{q})$ are the pseudo-charge densities.

Poor convergence with respect to the number of q-points.

Approximate it by an integral over a sphere of volume equivalent to that of the BZ

$$\langle \phi_{i\mathbf{k}} | \hat{v}_{\mathbf{x}}^{\mathsf{NL}} | \phi_{j\mathbf{k}} \rangle_{\mathsf{LR}} \simeq 2 \left(\frac{6\Omega^5}{\pi} \right)^{1/3} \sum_{l\mathbf{q}}^{\mathsf{occ}} w_{\mathbf{q}} \rho_{il}^*(\mathbf{q}) \rho_{lj}(\mathbf{q}).$$

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Applications

EXX Applied to

- Magnetic metals
- Semiconductors and insulators

Magnetic metals: introduction to the problem

Magnetic moment in Bohr magneton

Compound	FP-LDA	Experiment
FeAI	0.71	0.0

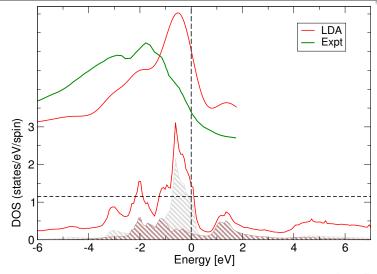
- **1** P. Mohn et al. Phys. Rev. Lett. 87 196401 (2001): LDA+U
- 2 Petukhov et al. Phys. Rev. B 67 153106 (2003): LDA+U+DMFT

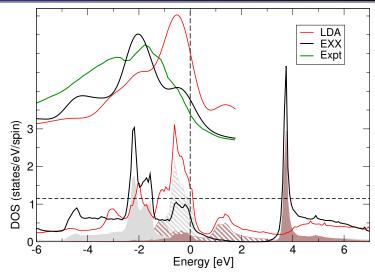
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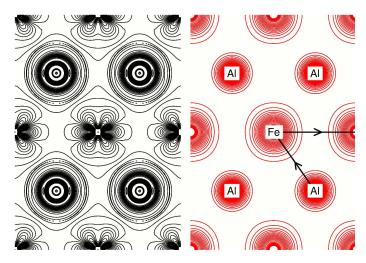
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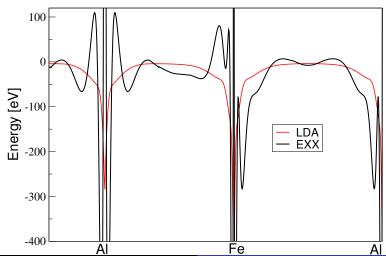
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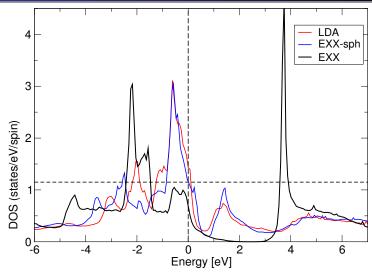
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Magnetic metals: stringent tests for EXX

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http://arxiv.org/abs/cond-mat/0501258



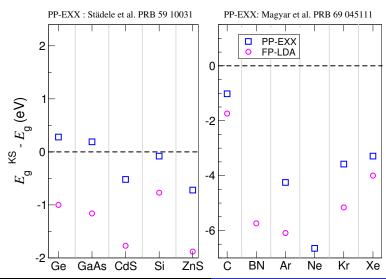
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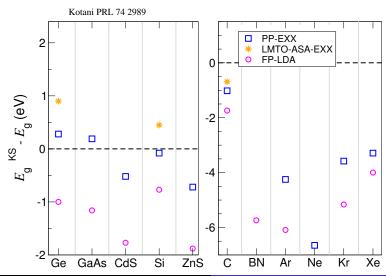
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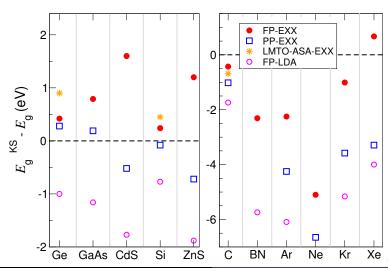
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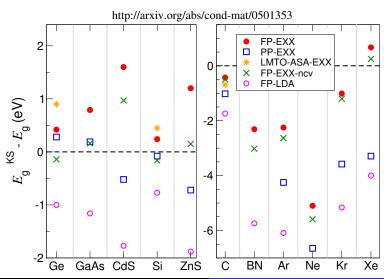
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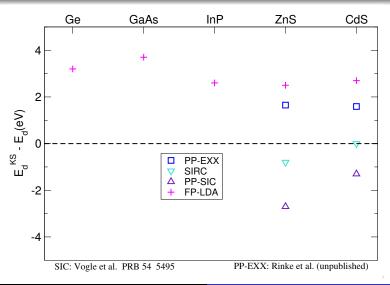






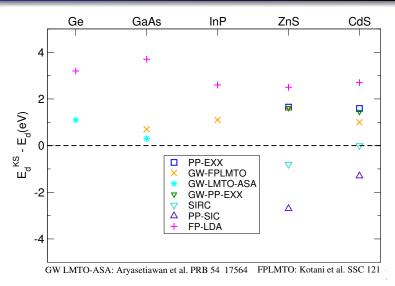


Semiconductors and insulators: d-band position

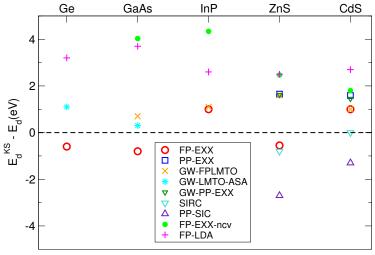




Semiconductors and insulators: d-band position



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http://arxiv.org/abs/cond-mat/0501353



- EXX within an all electron full potential method is implemented within EXC!TING code. Right now this is the only FP code to be able to do EXX.
- A new and one of the most optimal basis is proposed for calculating and inverting the response. This basis may be useful for future TD-DFT and GW calculations.
- Magnetic metals: Asymmetry in exchange potential is very important to get the correct ground-state.
- Semiconductors and insulators: Core-valence interaction is crucial for correct treatment of the EXX.
- Solution
 Lack of Asymmetry and/or core-valence interaction could lead to spurious agreement with experiments.



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- EXX within an all electron full potential method is implemented within EXC!TING code. Right now this is the only FP code to be able to do EXX.
- A new and one of the most optimal basis is proposed for calculating and inverting the response. This basis may be useful for future TD-DFT and GW calculations.
- Magnetic metals: Asymmetry in exchange potential is very important to get the correct ground-state.
- Semiconductors and insulators: Core-valence interaction is crucial for correct treatment of the EXX.
- Lack of Asymmetry and/or core-valence interaction could lead to spurious agreement with experiments.



Outlook

- **1** EXX can be generalised to handle non-collinear magnetism (derivatives w.r.t. $n_{\sigma\sigma'}(\mathbf{r})$).
- Future inclusion of exact correlation may be possible (multiconfiguration approach or adiabatic fluctuation dissipation)

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Code available at:

http://physik.kfunigraz.ac.at/~kde/secret_garden/exciting.html